

# Kurzpuls Laserquellen

Ursula Keller

*ETH Zurich, Physics Department, Switzerland*

*Power Lasers: Clean Tech Day  
swisslaser-net (SLN), [www.swisslaser.net](http://www.swisslaser.net)*

*ETH Zurich  
2. Juli 2009*

- **Good time resolution (short pulses)**  
measurements of fast processes
- **High pulse repetition rates**  
optical communication  
clocking and interconnects
- **High peak intensity at moderate energies**  
nonlinear optics  
precise material processing  
high field physics
- **Broad optical spectrum**  
frequency metrology (frequency comb)  
optical coherence tomography (OCT)

# Ultrafast Laser Oscillators in the Thin Disk Geometry

## A Power-Scalable Concept for Compact and Cost-Efficient fs and ps Lasers

▶ One of the major technology trends in laser research is the progress of ultrafast laser sources from complicated laboratory systems towards compact and reliable instruments. SESAM-modelocked ultrafast lasers using the thin disk geometry are a promising technology for this task.

### Introduction

Since the early 90s, the unique properties of

### ▶ THE AUTHORS

#### URSULA KELLER

Ursula Keller became an ETH professor in 1993, received the Ph. D. from Stanford University in 1989 and the Physics "Diplom" from ETH in 1984. She was a Member of Technical Staff (MTS) at AT&T Bell Laboratories in New Jersey from 1989 to 1993. She has

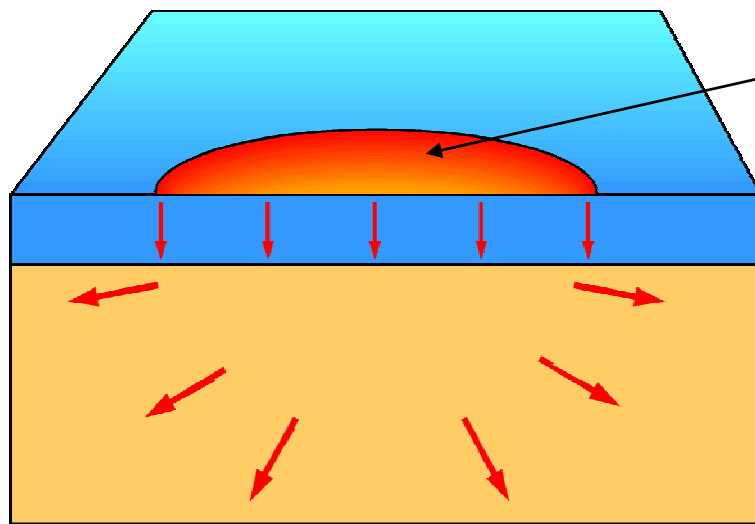
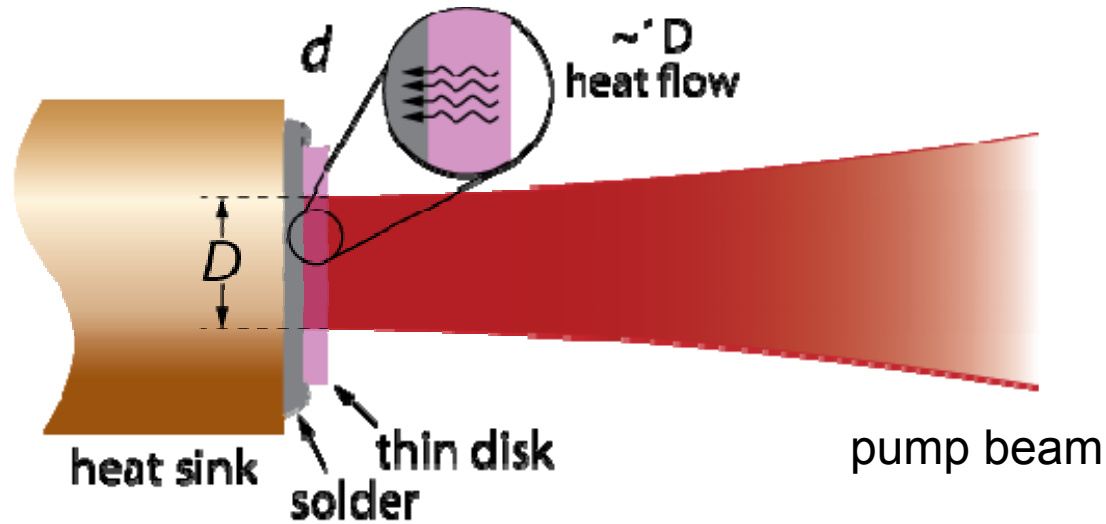


#### THOMAS SÜDMEYER

Thomas Südmeyer is head of the ultrafast laser section in Prof. Ursula Keller's group at ETH since 2005. He studied Physics at the University of Hanover and the Ecole Normale Supérieure, Paris, and obtained his Ph. D. from ETH in 2003 for his research on high



# ETH Thermal management with thin disk geometry



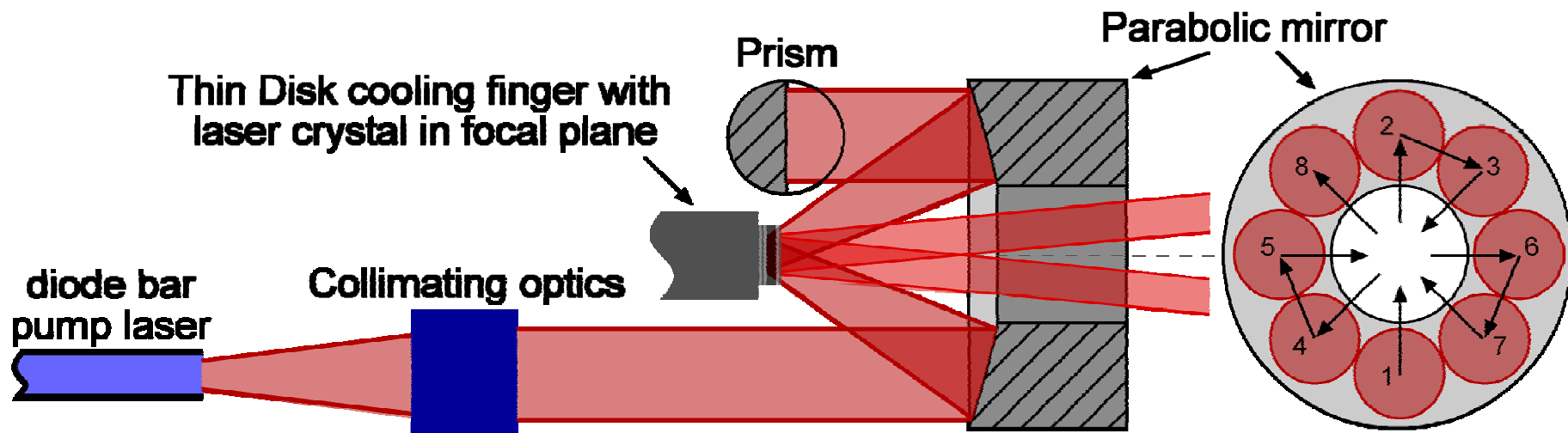
pump beam diameter  $2w$

thin disk with 1D heat flow  
thickness  $d$   
 $d \ll w$

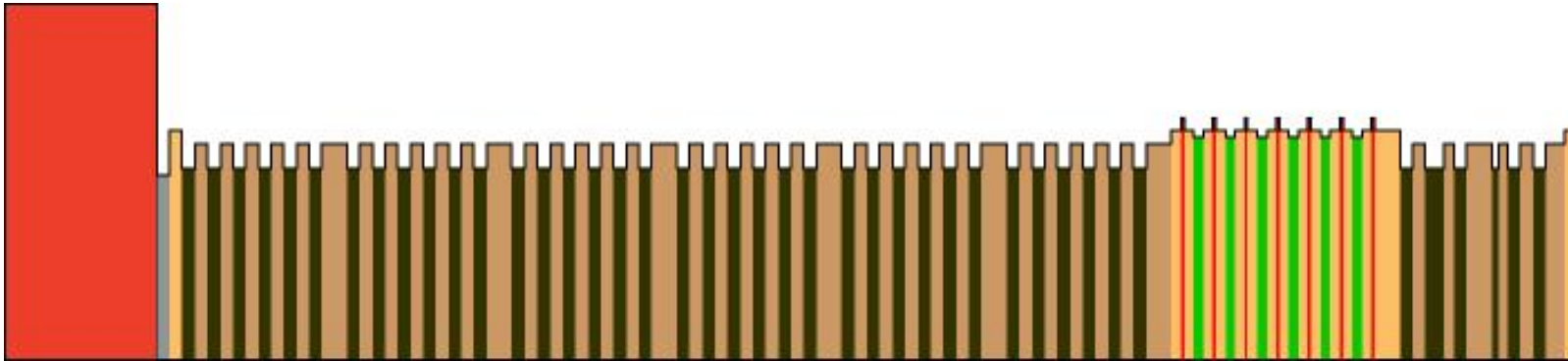
Power scaling with mode size

A. Giesen et al., *Appl. Phys. B* **58**, 365, 1994)

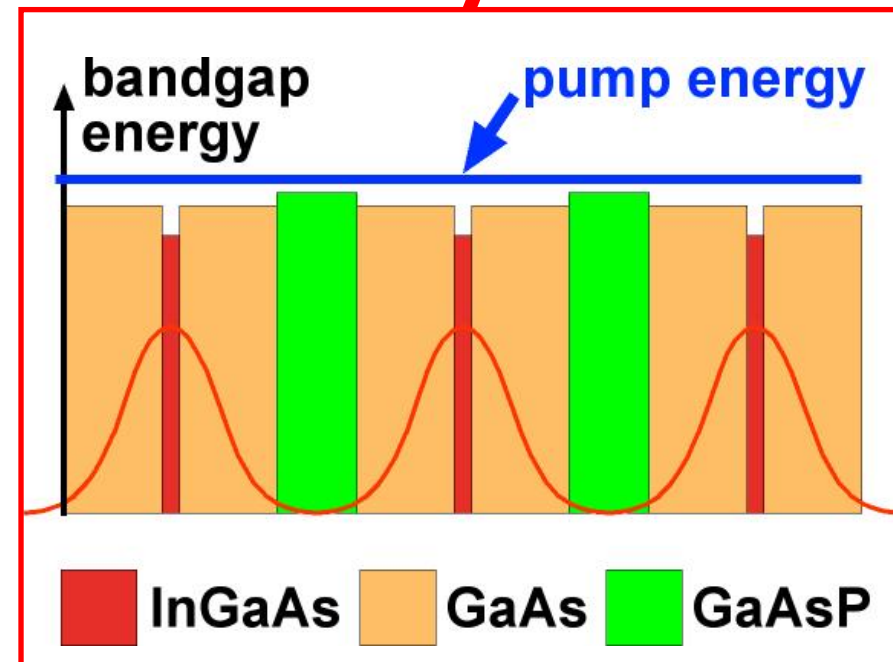
- Thickness of Yb:YAG disk: 100  $\mu\text{m}$  (absorption length a few mm - need multiple passes of pump for efficient absorption)
- Diameter of pump spot: 2.8 mm
- Pump power: up to 370 W @ 940 nm
- 16 passes of pump radiation through disk



## VECSEL gain structure: active region



- 7  $\text{In}_{0.13}\text{Ga}_{0.87}\text{As}$  QWs (8 nm) in anti-nodes of standing-wave pattern, designed for gain at  $\approx 950$  nm
- **GaAs** spacer layers
- Strain-compensating  $\text{GaAs}_{0.94}\text{P}_{0.06}$  layers
- Pump at 808 nm



# SESAM technology – ultrafast lasers for industrial application

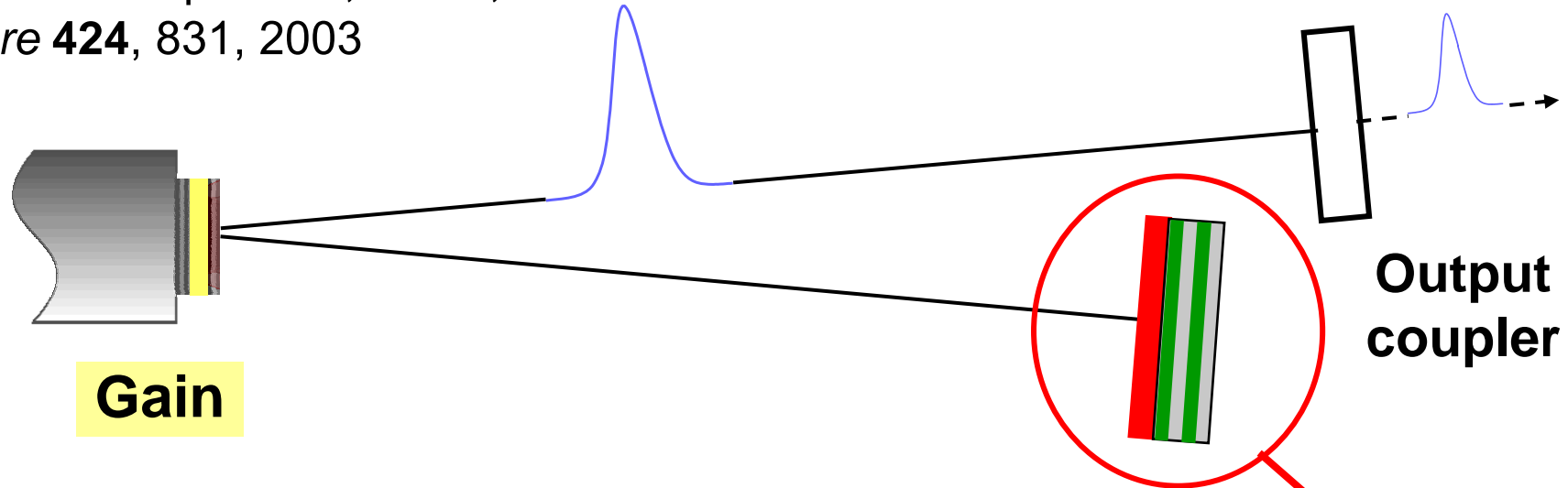
U. Keller et al. *Opt. Lett.* **17**, 505, 1992

*IEEE JSTQE* **2**, 435, 1996

*Progress in Optics* **46**, 1-115, 2004

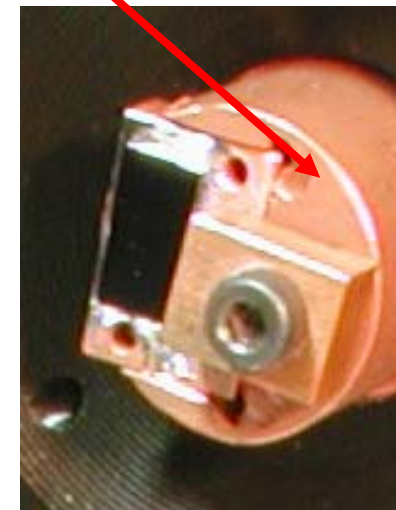
*Nature* **424**, 831, 2003

*SESAM solved Q-switching problem  
for diode-pumped solid-state lasers*

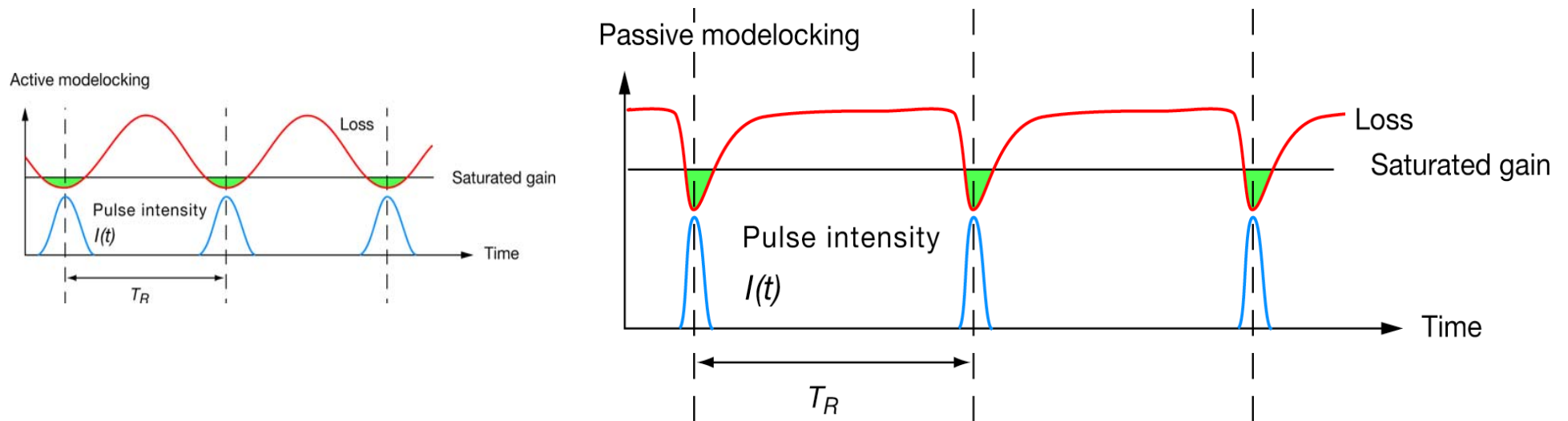
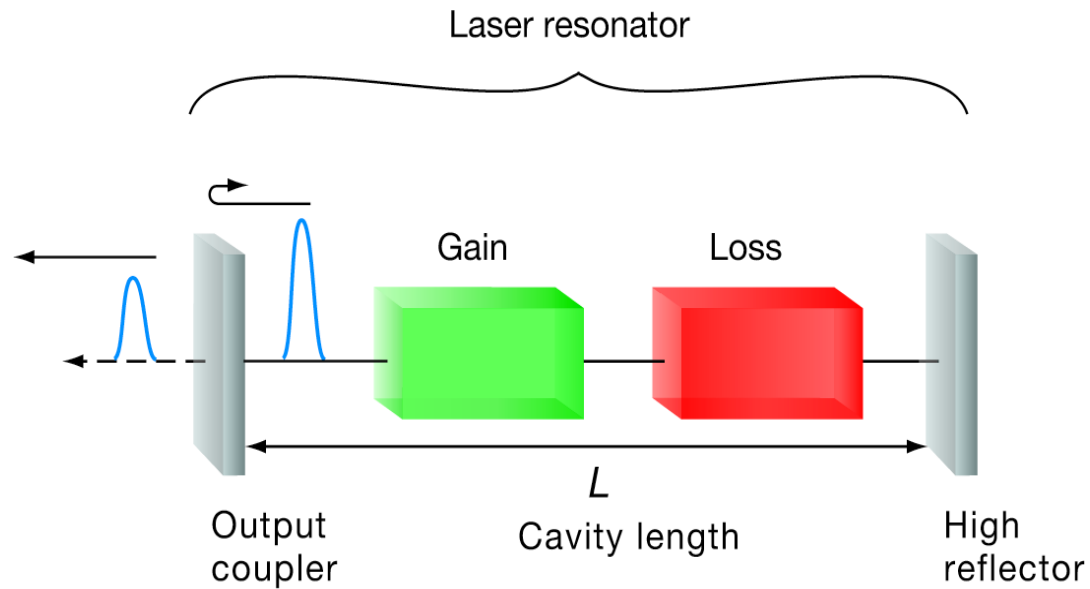


**SESAM**  
**SE**miconductor **S**aturable **A**bsorber **M**irror

self-starting, stable, and reliable modelocking of  
diode-pumped ultrafast solid-state lasers



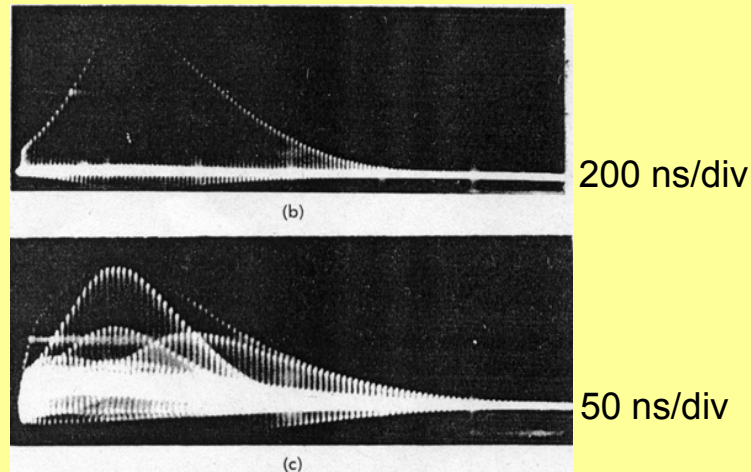
# Passive Modelocking





# Ultrashort pulse generation with modelocking

A. J. De Maria, D. A. Stetser, H. Heynau  
*Appl. Phys. Lett.* **8**, 174, 1966

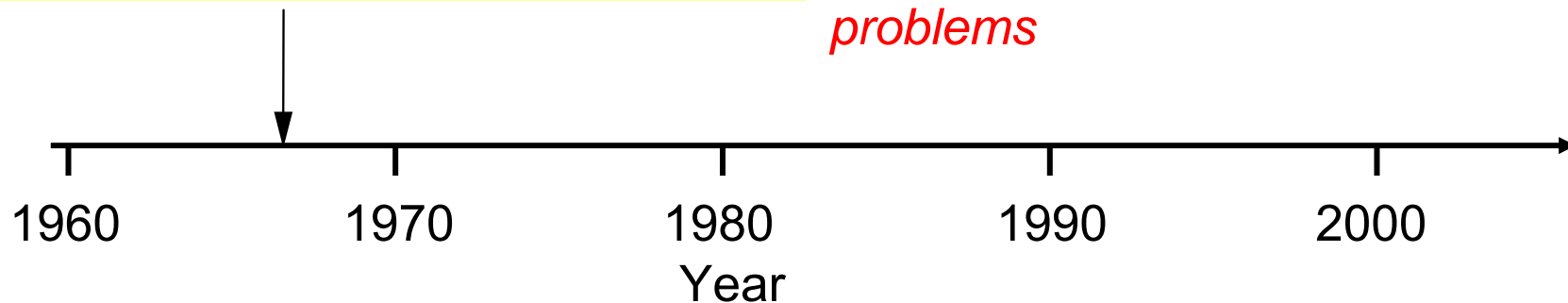


Nd:glass  
 first passively modelocked laser  
**Q-switched modelocked**

*Q-switching instabilities  
 continued to be a problem for solid-state  
 lasers until 1992 (i.e. for 26 years!)*

*Theoretical investigations in the 1970th  
 confirmed:  
 “ ... such solid-state lasers cannot  
 be passively modelocked ... ”*

*Dye lasers do not have Q-switching  
 problems*

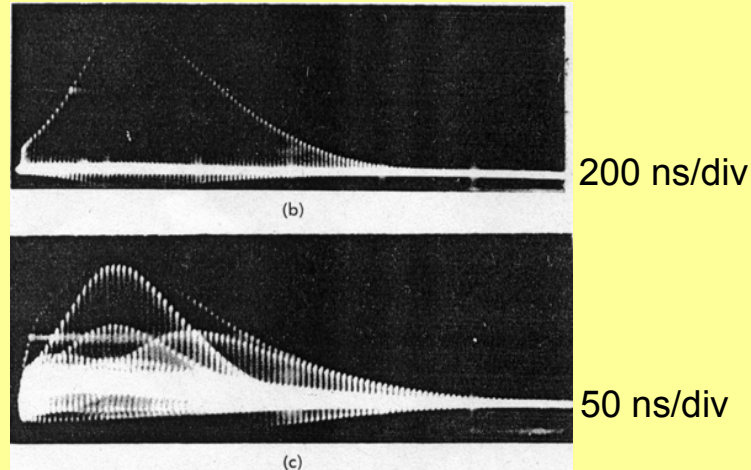


**Flashlamp-pumped  
 solid-state lasers**

**Diode-pumped solid-state lasers**  
 (first demonstration 1963)

# Ultrashort pulse generation with modelocking

A. J. De Maria, D. A. Stetser, H. Heynau  
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Nd:glass  
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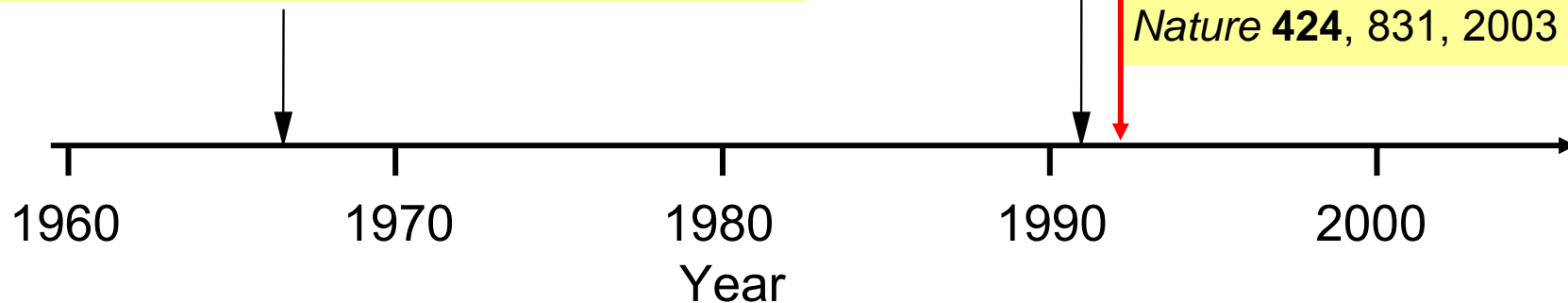
## SESAM

First passively modelocked  
 (diode-pumped) solid-state laser  
 without Q-switching

U. Keller et al.  
*Opt. Lett.* **17**, 505, 1992

*IEEE JSTQE* **2**, 435, 1996  
*Nature* **424**, 831, 2003

## KLM

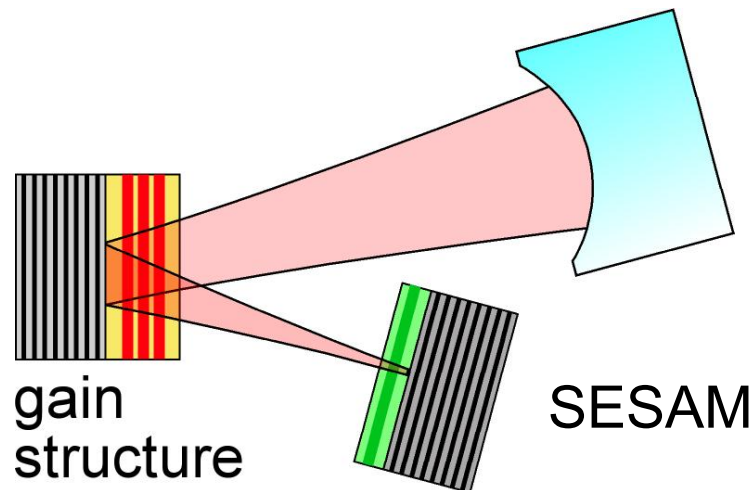


**Flashlamp-pumped  
 solid-state lasers**

**Diode-pumped solid-state lasers**  
 (first demonstration 1963)

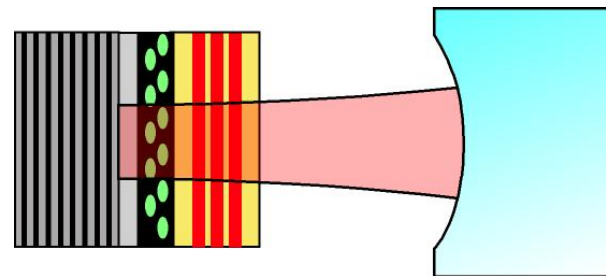
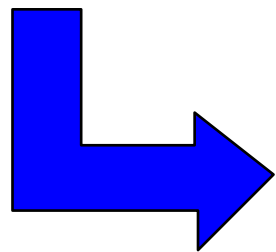
# Motivation for semiconductor lasers: Wafer scale integration

D. Lorensen et al., *Appl. Phys. B* **79**, 927, 2004



Passively modelocked VECSEL  
vertical external cavity surface emitting laser

Review: *Physics Reports* 429, 67-120, 2006

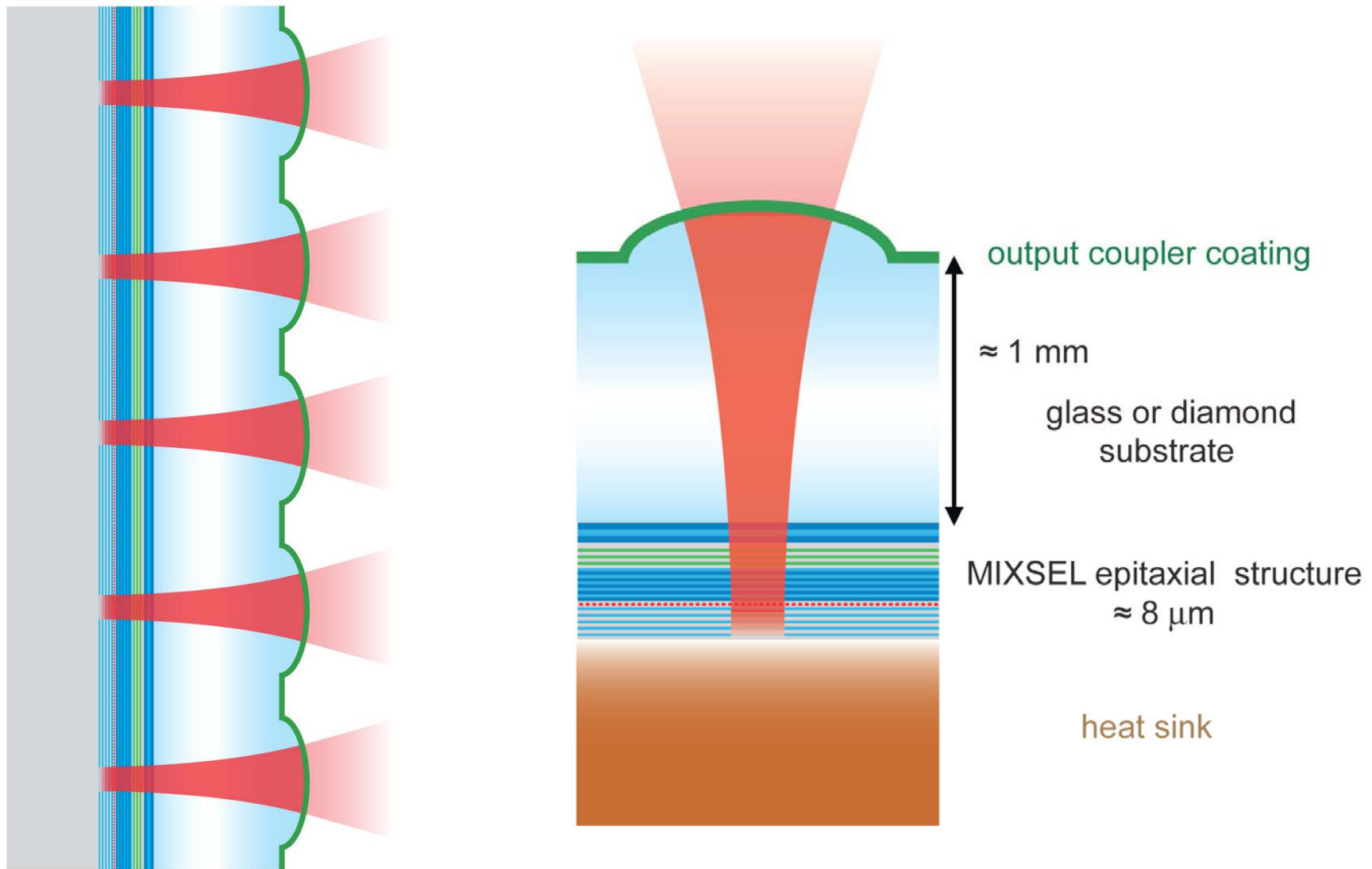


MIXSEL

modelocked integrated external-cavity surface emitting laser

D. J. H. C. Maas et al., *Appl. Phys. B* **88**, 493, 2007

# MIXSEL wafer scale integration



A. R. Bellancourt et al., "Modelocked integrated external-cavity surface emitting laser"  
*IET Optoelectronics*, vol. 3, Iss. 2, pp. 61-72, 2009 (invited paper)

# Optical amplifier

Laser oscillator

pulse energy: typically nanojoule level ( $\approx 1$  nJ)  
pulse repetition rate: typically 100 MHz

Laser amplifier

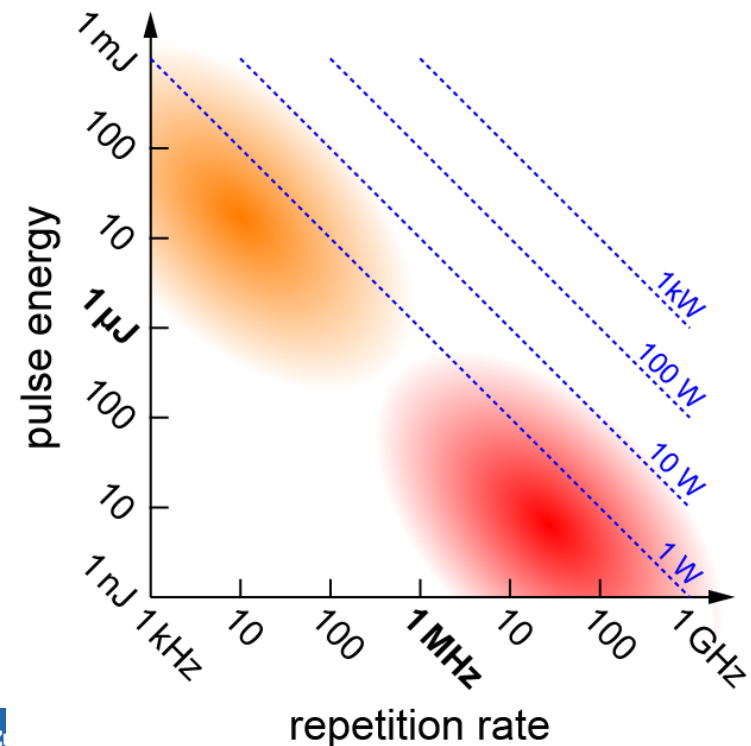
pulse energy: mJ to J  
pulse repetition rate: Hz to 1 kHz (10 kHz)

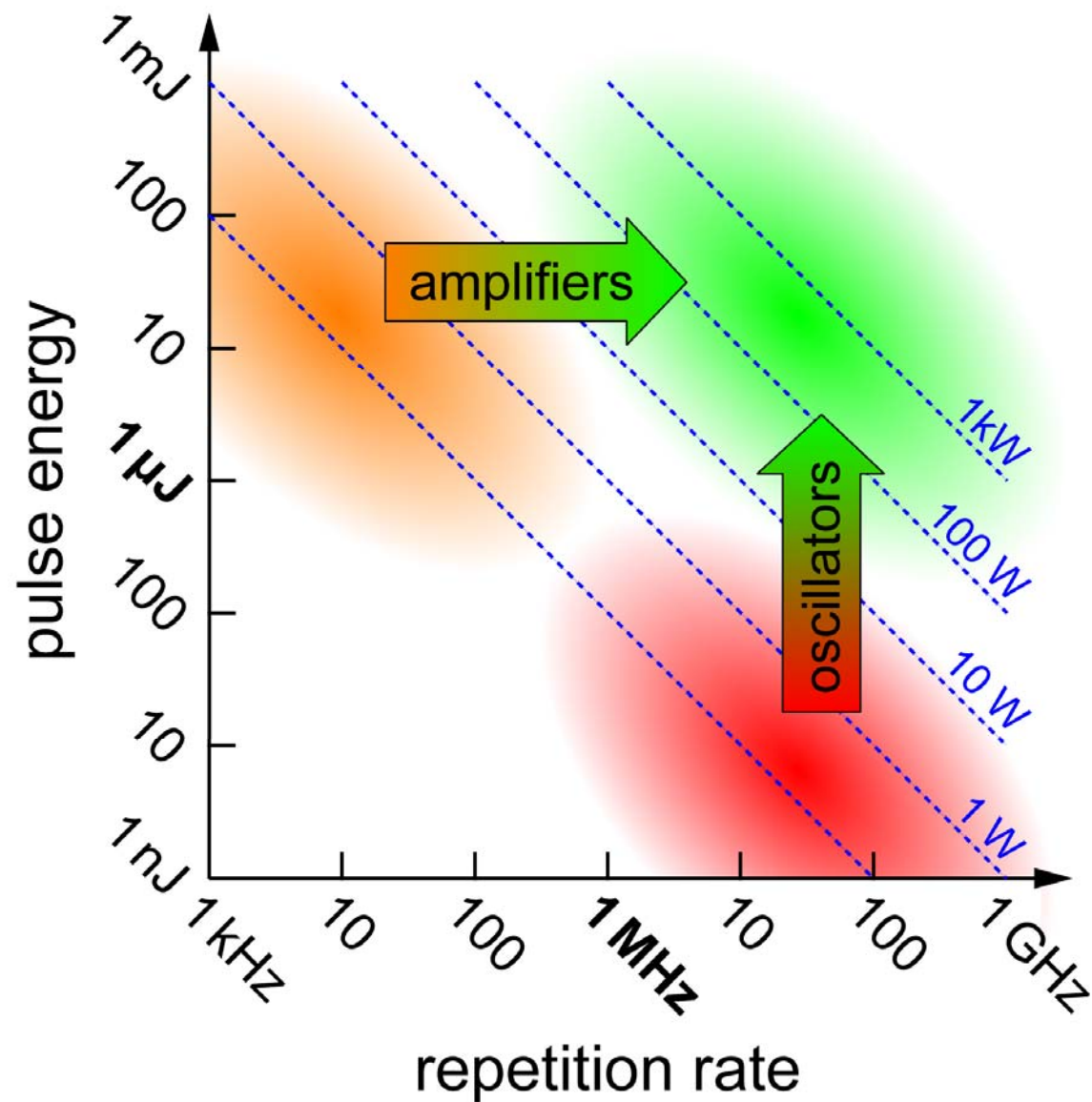
$$P_{av} = E_p f_{rep}$$

$$E_p = 10 \text{ nJ} \Rightarrow 1 \text{ mJ} \quad (\times 10^5)$$

$$f_{rep} = 100 \text{ MHz} \Rightarrow 1 \text{ kHz} \quad (\times 10^{-5})$$

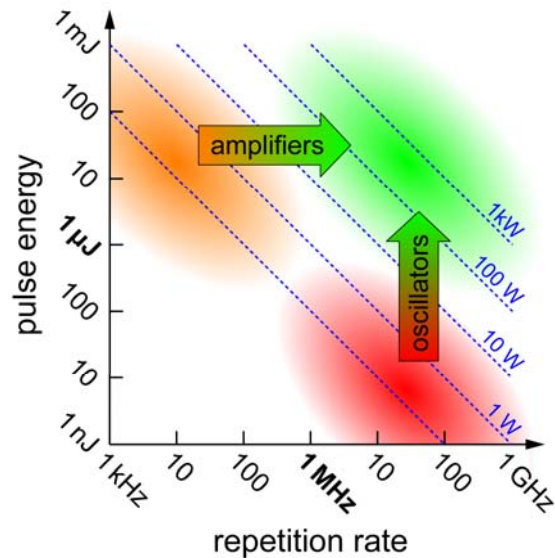
$$P_{av} = 1 \text{ W} \Rightarrow 1 \text{ W}$$



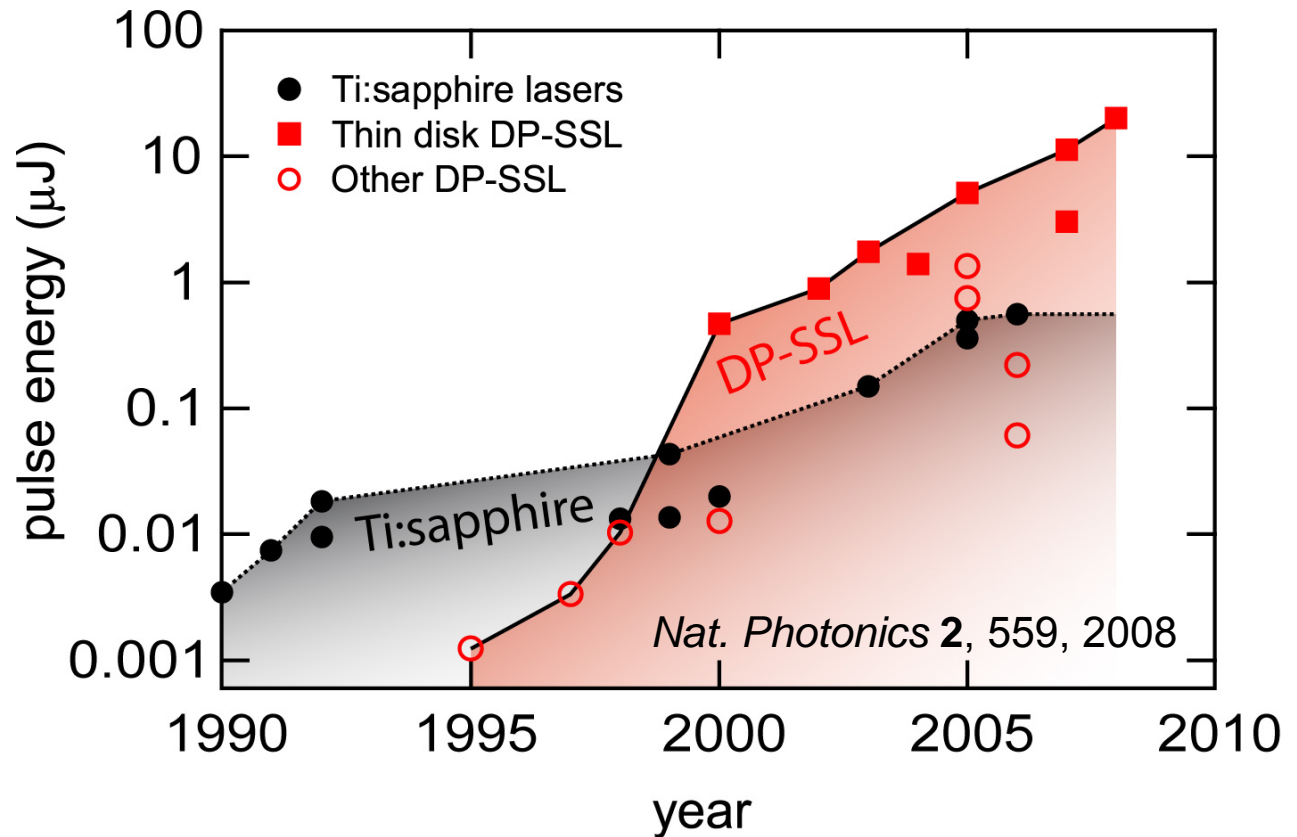


T. Südmeyer et al., *Nature Photonics* 2, 599, 2008

# High average power lasers



DP-SSL: diode-pumped solid-state lasers



**First time  $>10 \mu\text{J}$**  pulse energy from a SESAM modelocked Yb:YAG thin disk laser:  
*Opt. Express* **16**, 6397, 2008 and *CLEO Europe* June 2007

**26  $\mu\text{J}$**  with a multipass gain cavity and larger output coupling of 70% (Trumpf/Konstanz)  
*Opt. Express* **16**, 20530, 2008

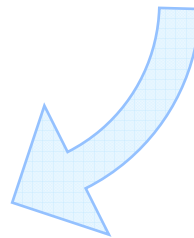




First cw modelocked thin-disk laser (Yb:YAG):  
16 W, 730 fs, 0.5 MW

J. Aus der Au et al., *Opt. Lett.* **25**, 859 (2000)

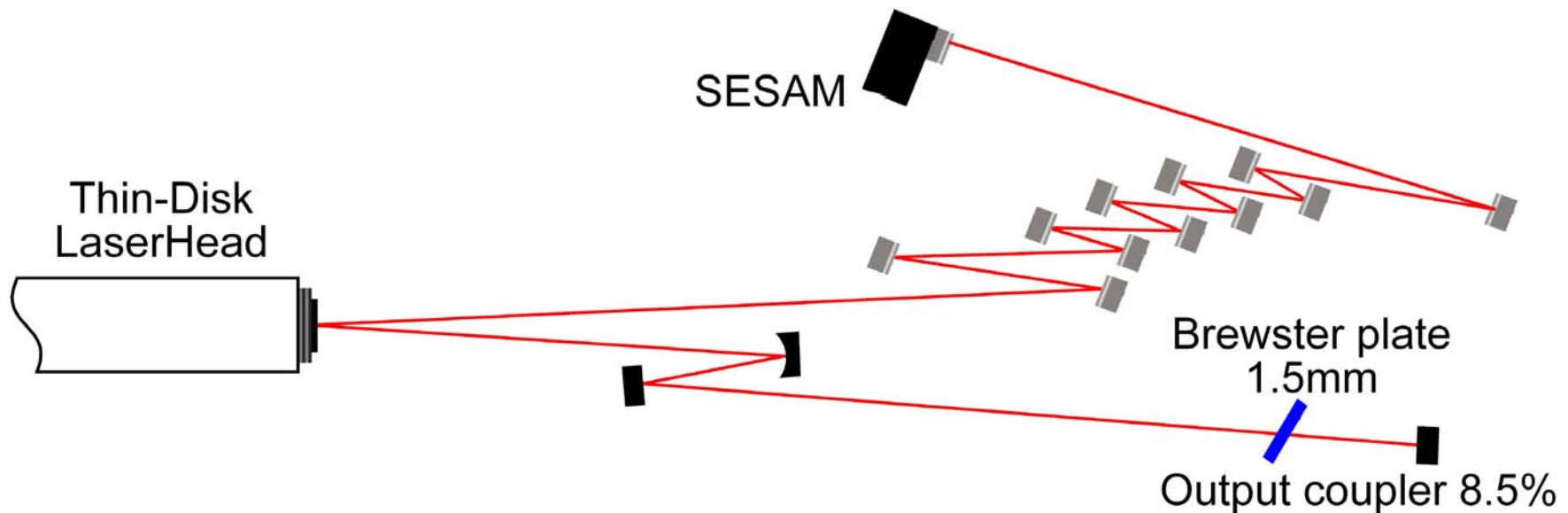
Power scaling



80 W, 705 fs, 1.75 MW

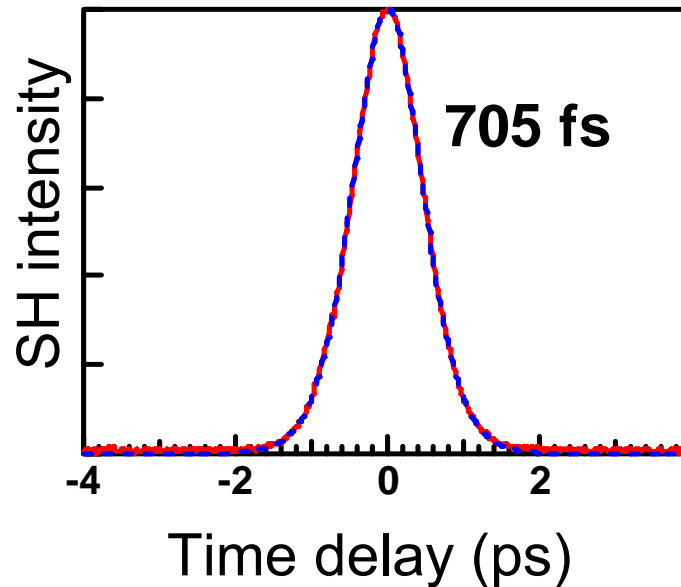
E. Innerhofer et al.,  
*Laser Phys. Lett.* **1**, 1 2004

# Thin disk laser: 57-MHz setup

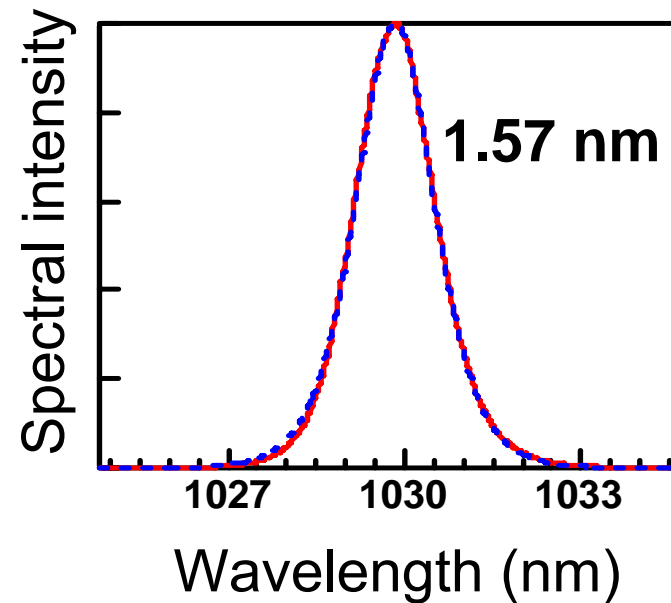


- Thin disk **as folding mirror**
- SESAM and output coupler **as end mirror**
- **Brewster plate** for linear polarization
- **Negative group delay dispersion** from GTI-type dispersive mirrors

## Autocorrelation



## Optical spectrum



$$P_{\text{avg}} = 80 \text{ W}$$

$$\tau_p = 705 \text{ fs}$$

$$f_{\text{rep}} = 57 \text{ MHz}$$

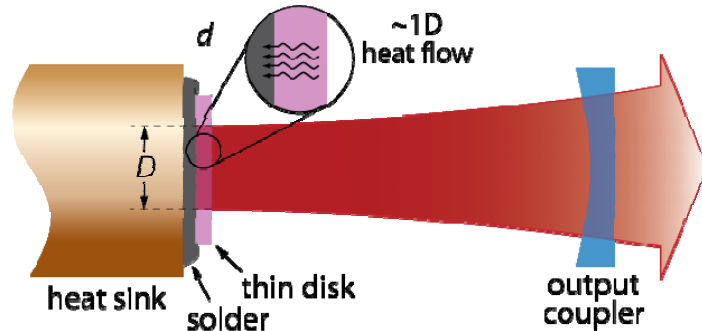
$$E_p = 1.4 \text{ } \mu\text{J}$$

$$P_{\text{peak}} = 1.75 \text{ MW}$$

$$\Delta\nu \tau_p = 0.32$$

First modelocked (ML) thin-disk, 16 W: *Optics Lett.* **25**, 859, 2000  
 60 W ML Thin Disk: E. Innerhofer et al., *Optics Lett.* **28**, 367, 2003  
 80 W ML Thin Disk: F. Brunner et al., *Optics Lett.* **29**, 1921, 2004

## Thin disk laser



## SESAM

semiconductor saturable absorber  
mirror



## A power scalable concept:

**Scale output power by equally increasing the pump power and mode sizes on disk and SESAM.**

→ no increase of the temperature, no increase of the tendency for QML

**16 W**, 35 MHz, 730 fs, 0.47  $\mu$ J, 0.6 MW  
J. Aus der Au, et al., *Opt. Lett.* **25**, 859 (2000)



**power scaling**

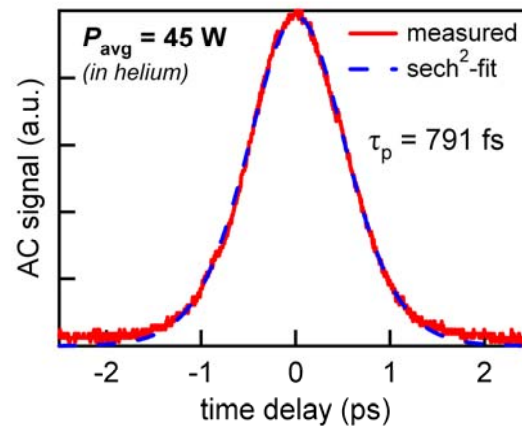
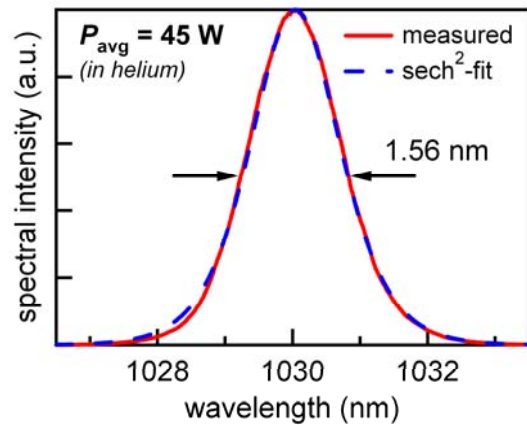
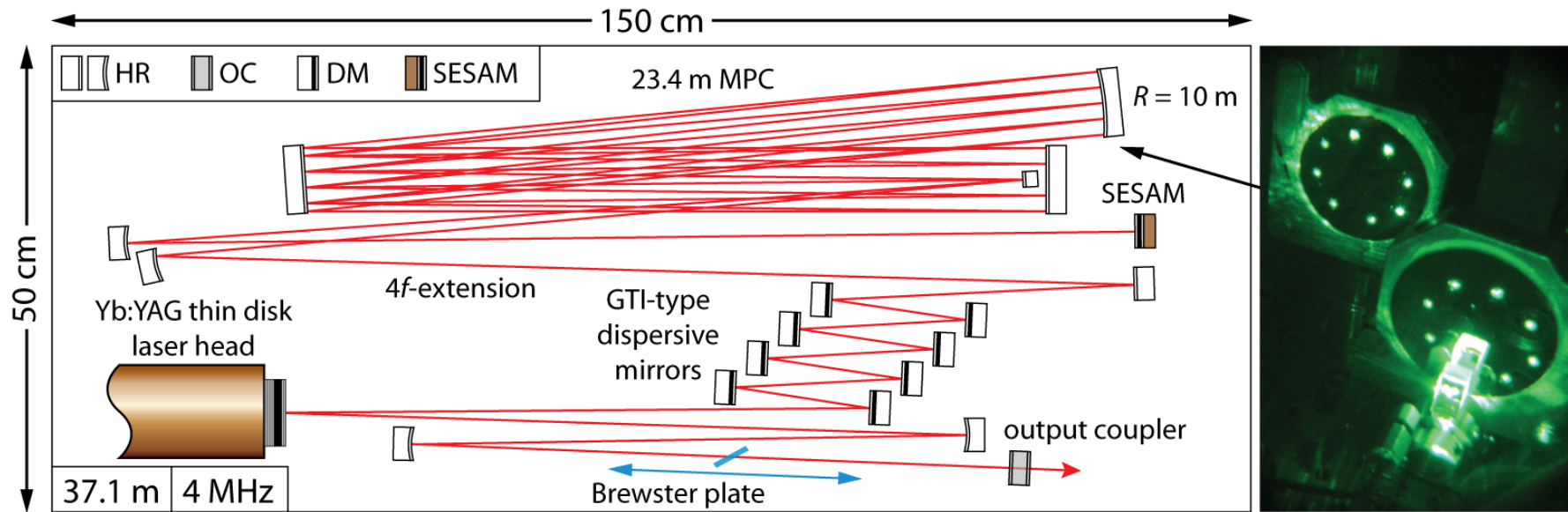


**80 W**, 57 MHz, 705 fs, 1.4  $\mu$ J, 1.75 MW  
F. Brunner, et al., *Opt. Lett.* **29**, 1921 (2004)

- 1<sup>st</sup> ML thin disk laser (Yb:YAG)
- pump diameter 1.2 mm

- pump diameter 2.8 mm

# 11 $\mu\text{J}$ SESAM modelocked Yb:YAG thin disk laser



*Opt. Express* 16, 6397, 2008

$$P_{\text{avg}} = 45 \text{ W}$$

$$f_{\text{rep}} = 4 \text{ MHz}$$

$$E_p = 11.3 \mu\text{J}$$

$$\lambda = 1030 \text{ nm}$$

$$\Delta\lambda = 1.56 \text{ nm}$$

$$M^2 = 1.1$$

$$P_{\text{peak}} = 12.5 \text{ MW}$$

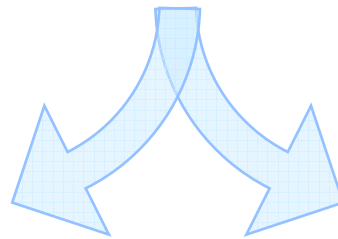
$$\tau_p = 791 \text{ fs}$$

$$\tau_p \cdot \Delta\nu = 0.35 \text{ (ideal 0.315)}$$

First cw modelocked thin-disk laser (Yb:YAG):  
16 W, 730 fs, 0.5 MW

J. Aus der Au et al., *Opt. Lett.* **25**, 859 (2000)

Power scaling



80 W, 705 fs, 1.75 MW

E. Innerhofer et al.,  
*Laser Phys. Lett.* **1**, 1 2004

Pulse duration reduced  
with different laser  
materials:

Yb:KYW

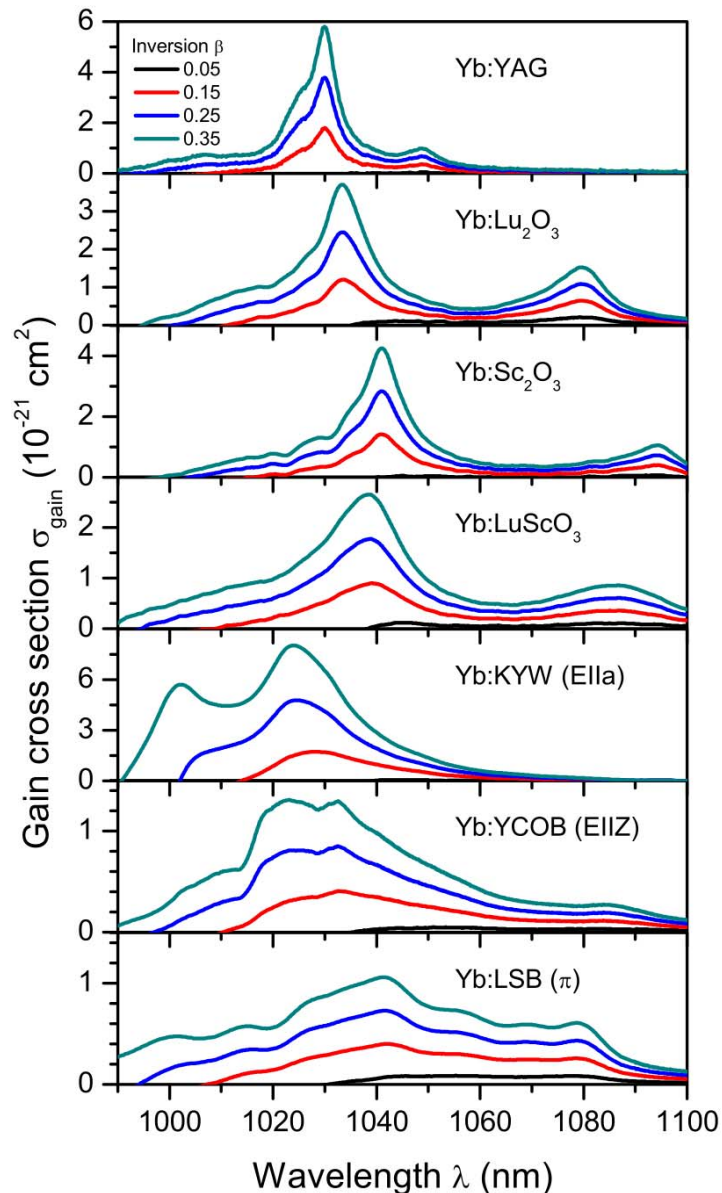
22 W, 240 fs, 3.3 MW

F. Brunner et al.,  
*Opt. Lett.* **27**, 1162 (2002)

Yb:Lu<sub>2</sub>O<sub>3</sub>

20.5 W, 370 fs, 0.75 MW

S. V. Marchese et al.,  
*Opt. Exp.* **15**, 16966 (2007)



$$\sigma_{gain} = \beta\sigma_{em} - (1 - \beta)\sigma_{abs}$$

**Yb:garnets: Yb:YAG, Yb:LuAG ...**

relatively small gain bandwidth

**Yb:sesquioxides: Yb:RE<sub>2</sub>O<sub>3</sub>**

RE = Y, Sc or Lu

difficult crystal growth resolved

Yb:Lu<sub>2</sub>O<sub>3</sub>      63 W, 535 fs (CLEO 09)

Yb:Sc<sub>2</sub>O<sub>3</sub>

Yb:LuScO<sub>3</sub>      7.2 W, 227 fs (CLEO 09)

**Yb:tungstates: ARE(WO<sub>4</sub>)<sub>2</sub>**

A = alkali ion, e.g. K, Na

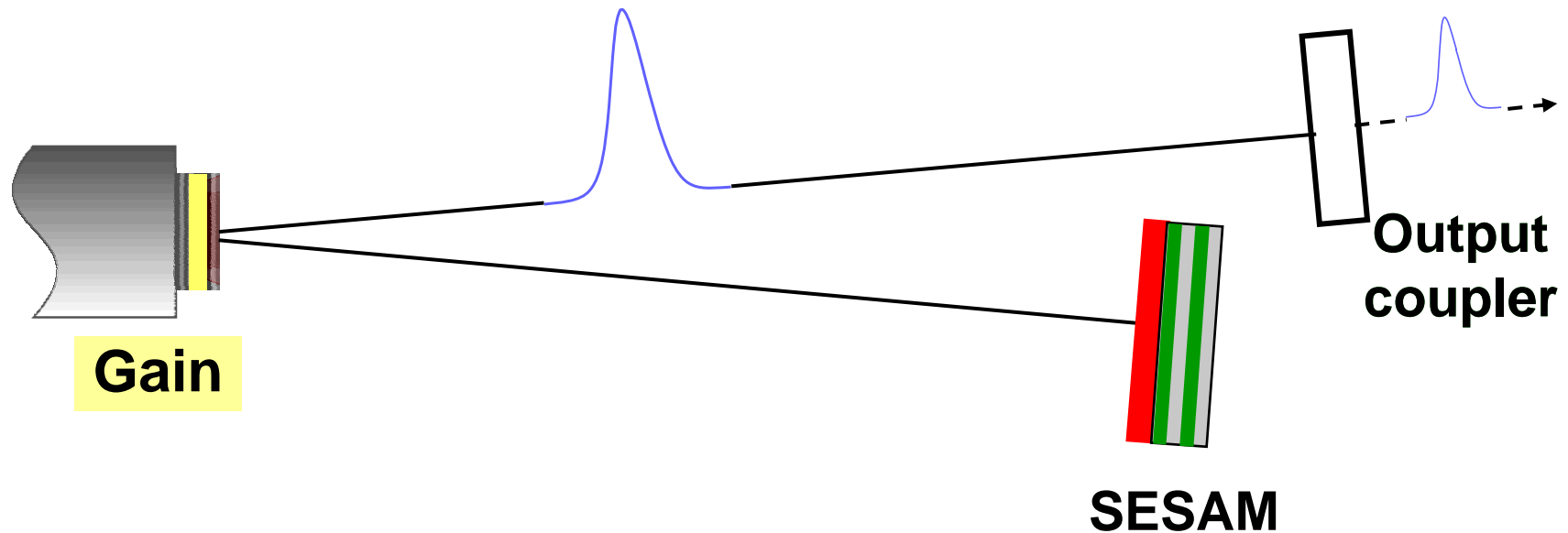
RE = Gd, Lu and Y

“Yb:KYW, Yb:NYW, Yb:NGW”

strong anisotropy of thermo-mechanical prop.

**Yb:borates** (disordered crystal structure)

Yb:YCOB, Yb:LSB



Short cavity length = high pulse repetition rate

Pulse repetition rate is given by the cavity round trip time.

**1 GHz:** cavity round trip time 1 ns and a cavity length **15 cm**.

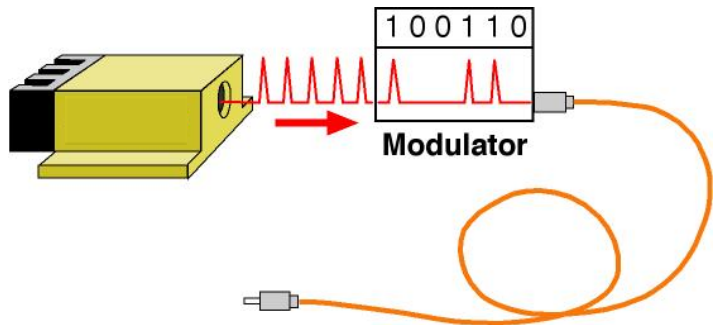
**1 THz:** cavity round trip time 1 ps and a cavity length **150  $\mu\text{m}$** .

No high speed electronics needed.

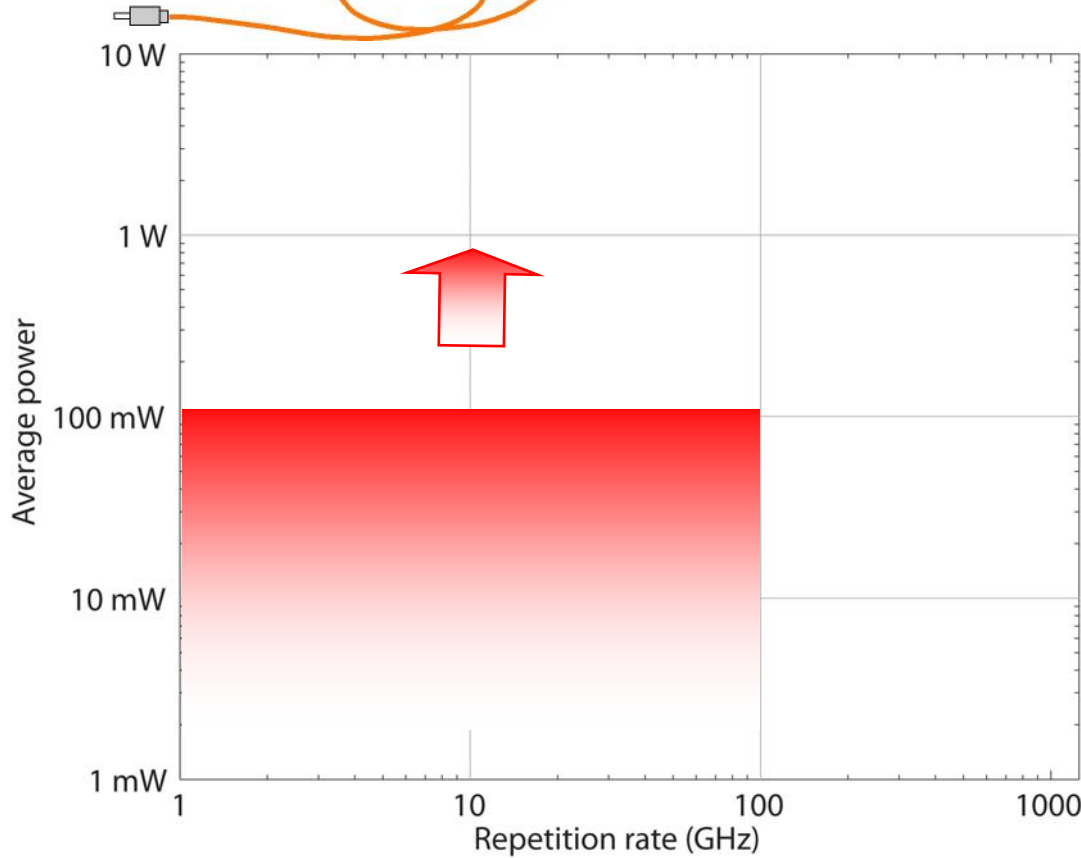
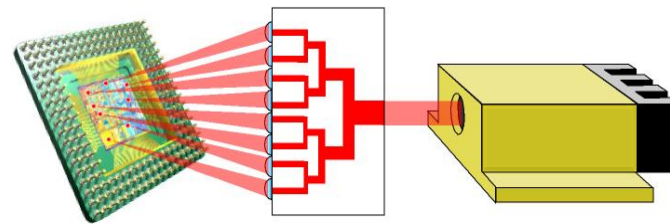


# Compact ultrafast lasers for “real world application”

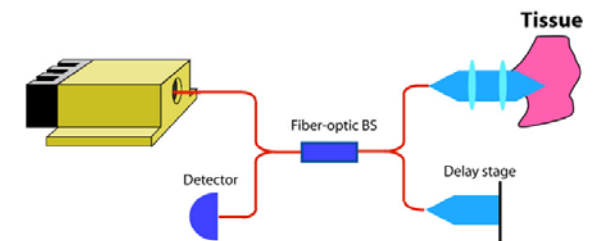
Telecom



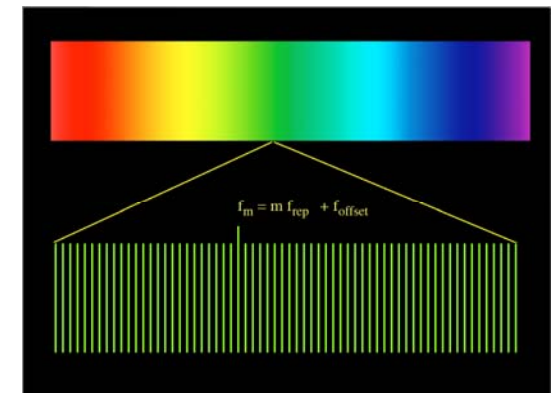
Optical Clocking



Biomedical applications

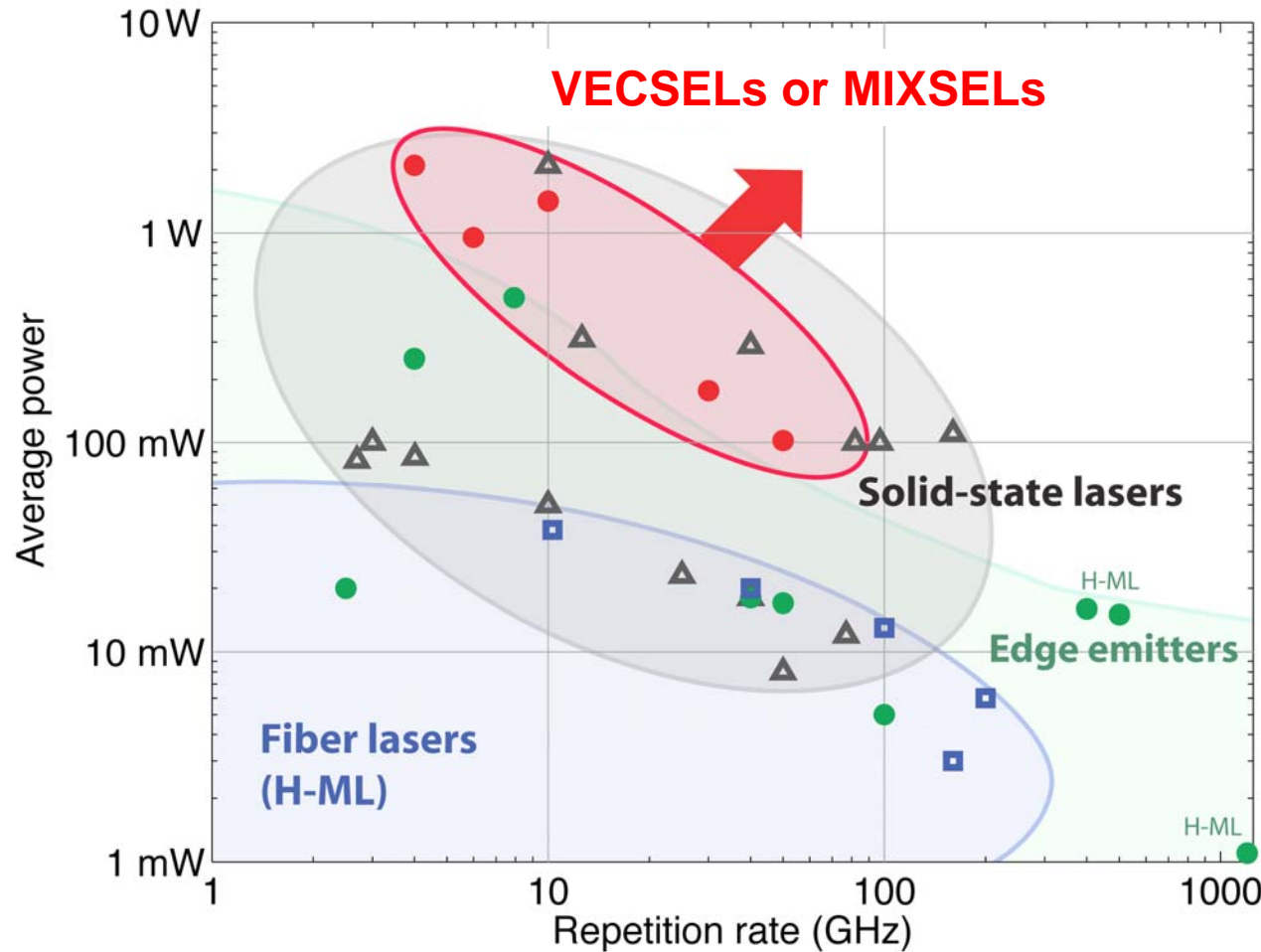


Frequency comb

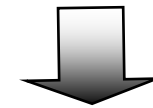
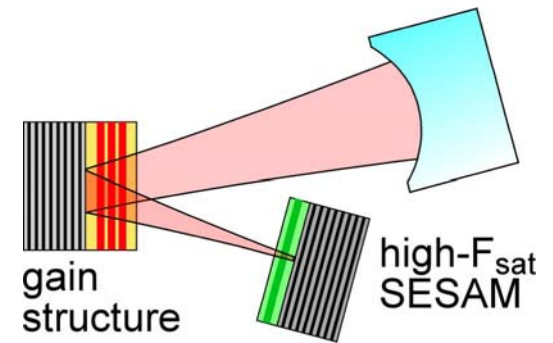


# Comparison of Ultrafast GHz Lasers

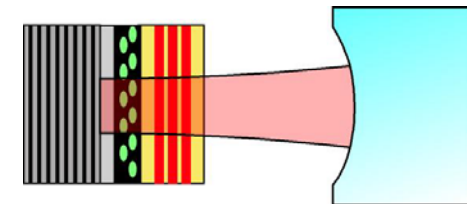
Vertical external cavity surface emitting laser (VECSEL) or semiconductor thin disk laser



Modelocked VECSEL



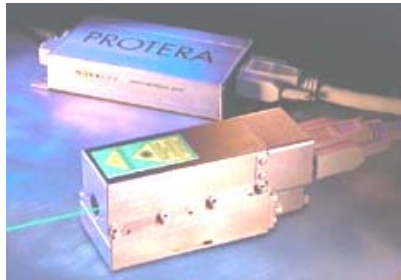
MIXSEL



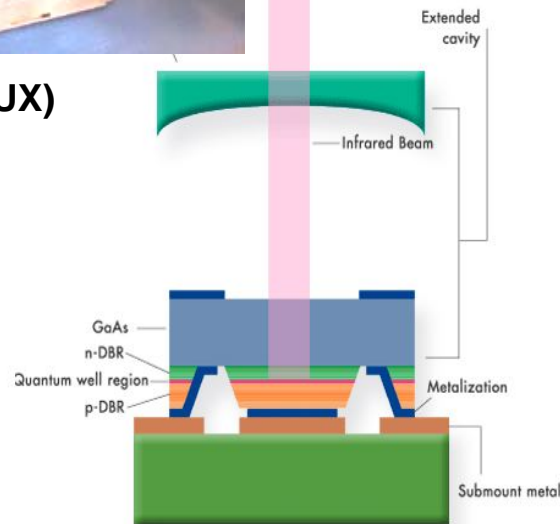
Review article: U. Keller and A. C. Tropper, Physics Reports, vol. 429, Nr. 2, pp. 67-120, 2006

# Electrical or optical pumping ?

Medium to high powers with good beam quality



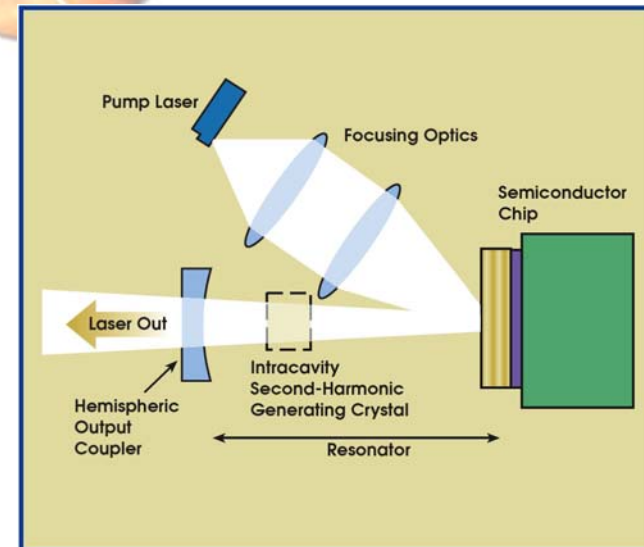
(NOVALUX)



**Electrically pumped**  
**Medium power:**  
**up to 500 mW (TEM<sub>00</sub>)**

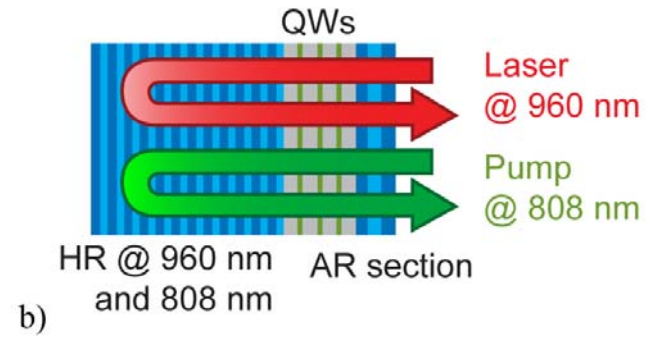
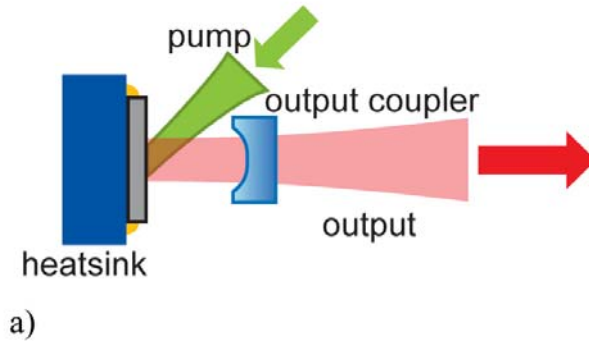


(COHERENT)

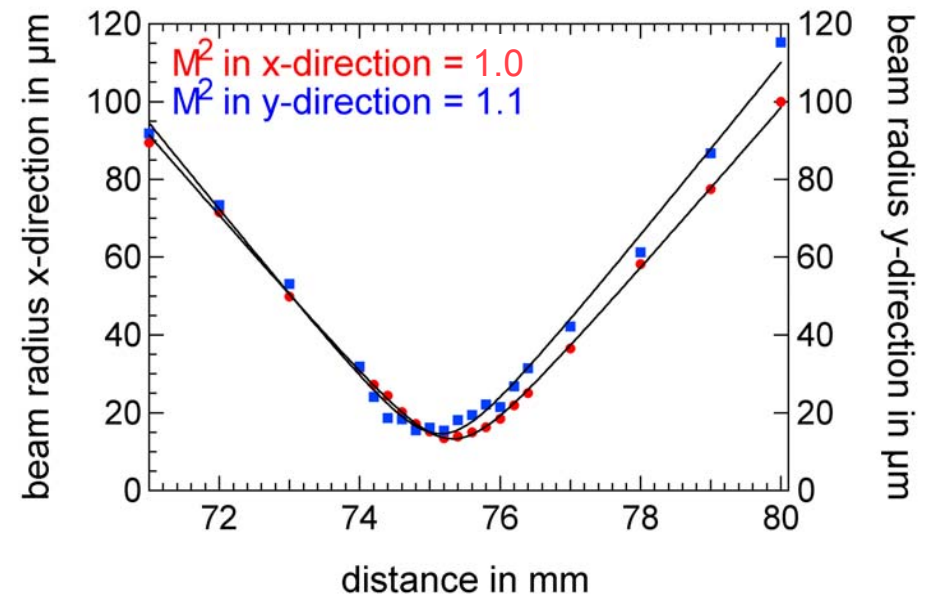
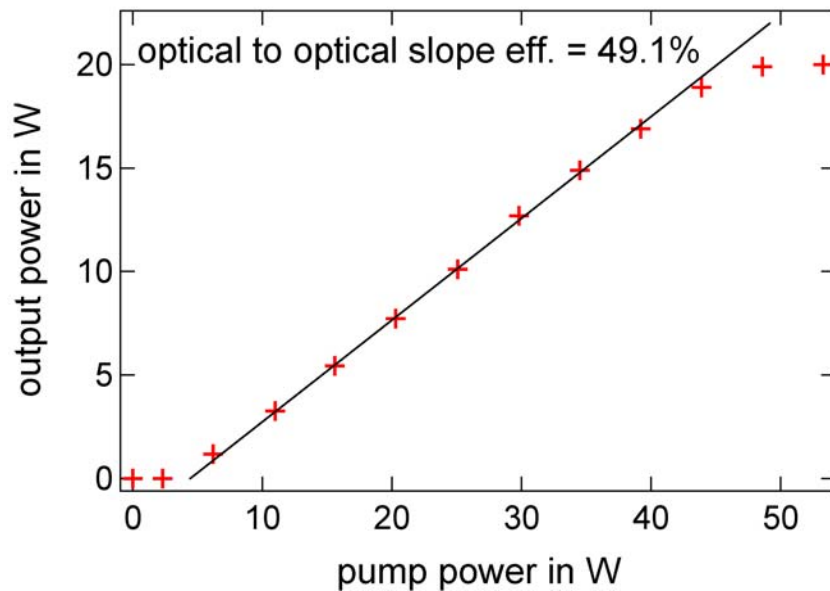


**Optically pumped**  
**High power:**  
**up to 30 W (M<sup>2</sup> = 3)**

# 20 W cw OP-VECSEL ( $M^2 \approx 1$ )



20.2 W cw at 50 W pump power



B. Rudin, A. Rutz, M. Hoffmann, D. J. H. C. Maas, A.-R. Bellancourt, E. Gini, T. Südmeyer, U. Keller  
*Optics Lett.* **33**, 2719, 2008

# Electrical vs. optical pumping

OP-VECSEL

EP-VECSEL

Output coupler

Pump laser

Active region

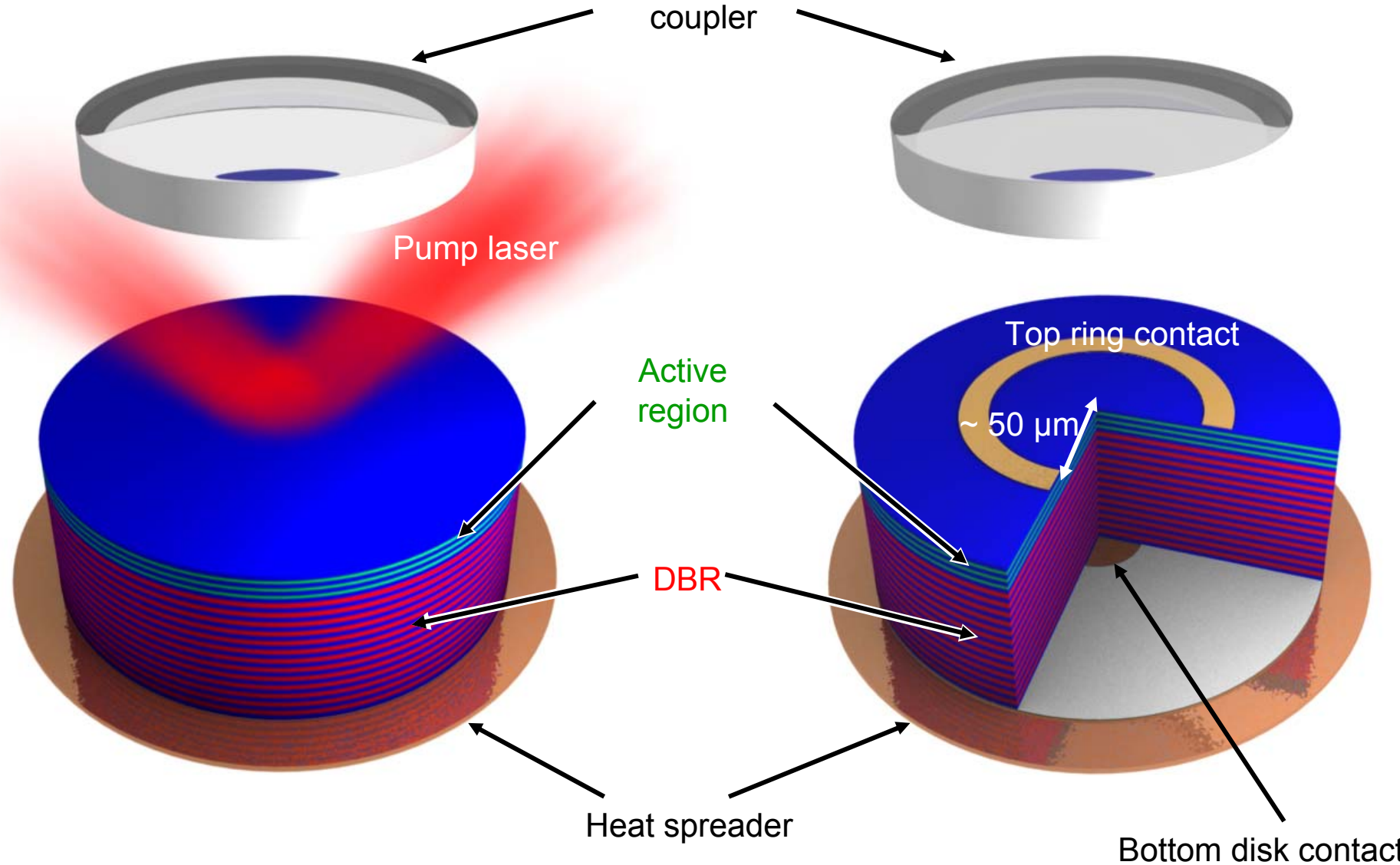
DBR

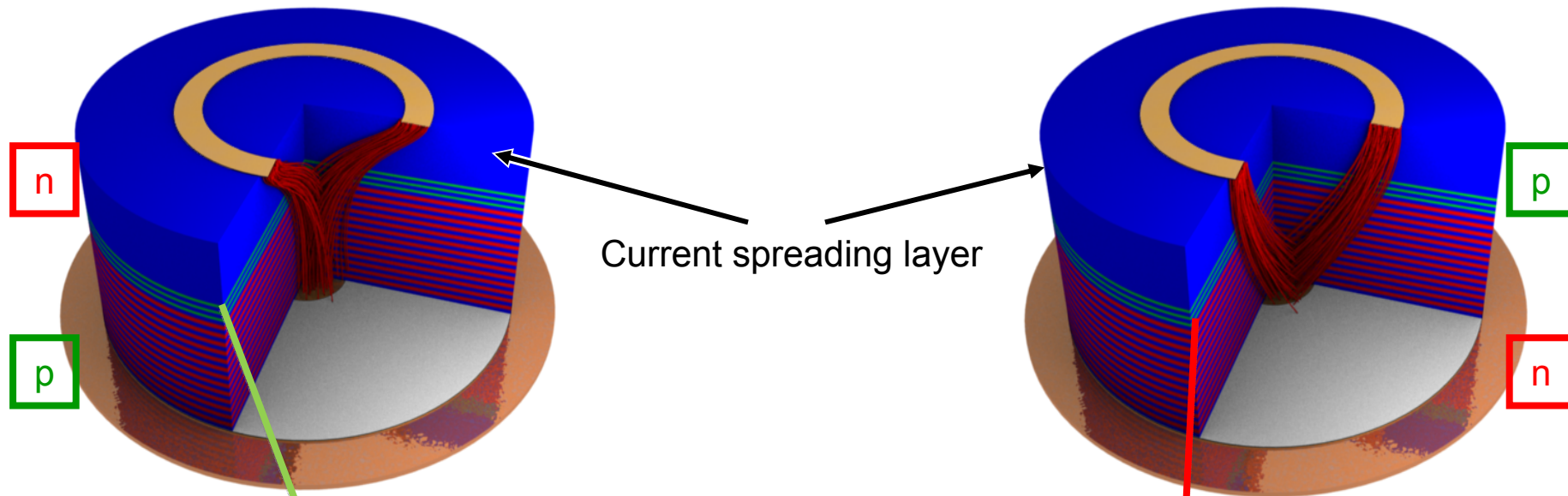
Heat spreader

Top ring contact

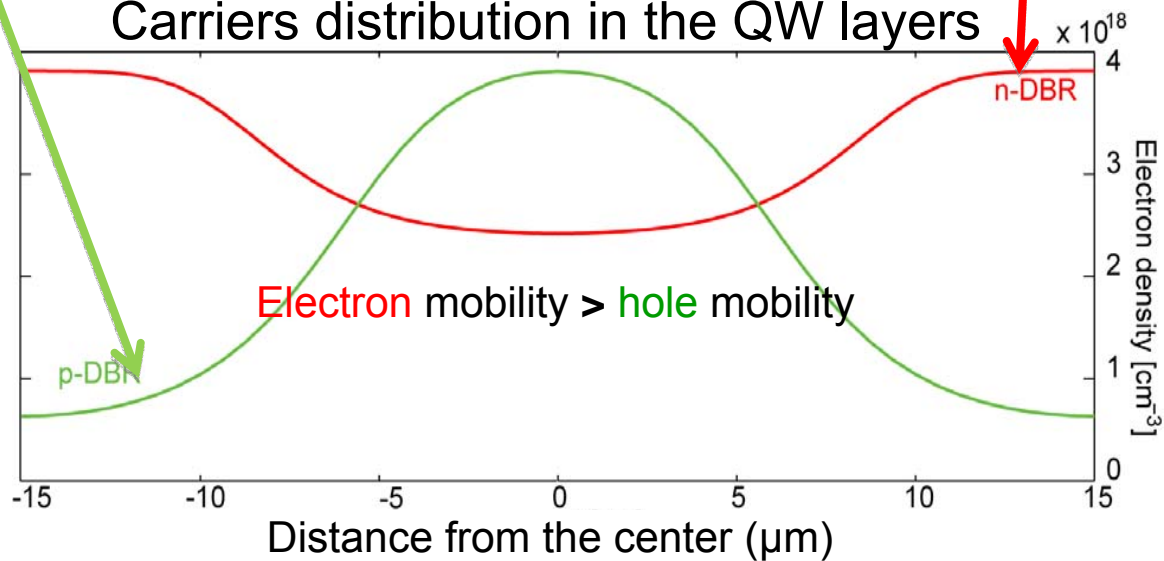
~ 50  $\mu\text{m}$

Bottom disk contact





Carriers distribution in the QW layers

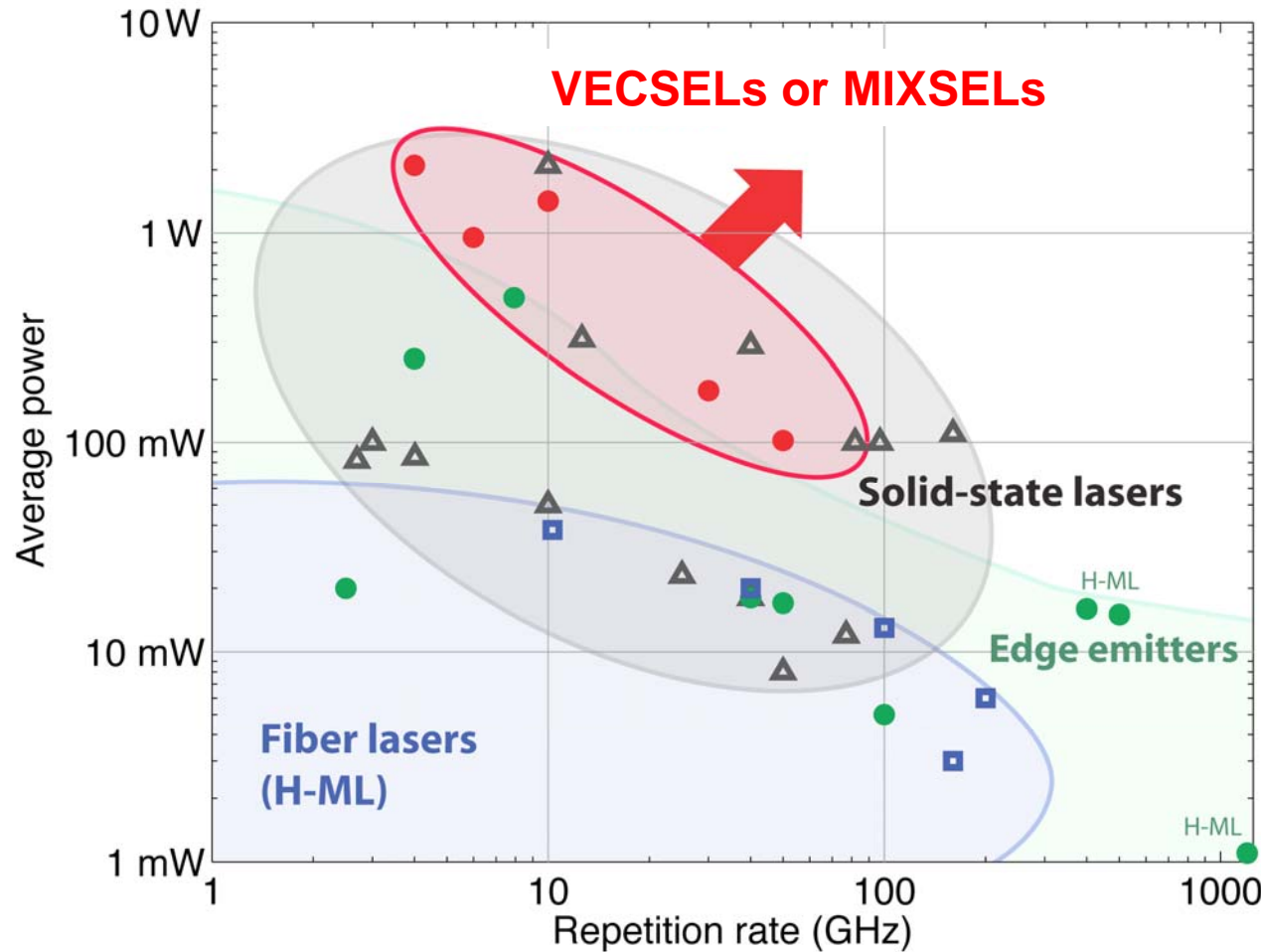


p-DBR design favorable for large output beam with fundamental transverse mode

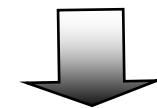
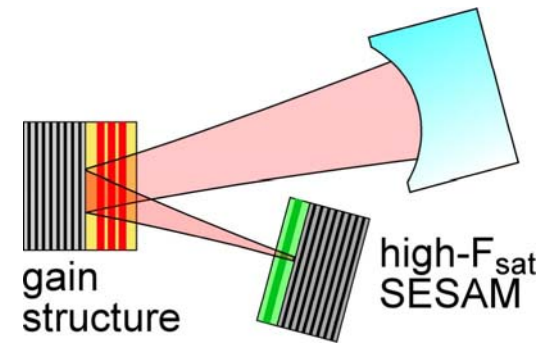
P. Kreuter et al., *Appl. Phys. B*, **91**, 257, 2008

# Comparison of Ultrafast GHz Lasers

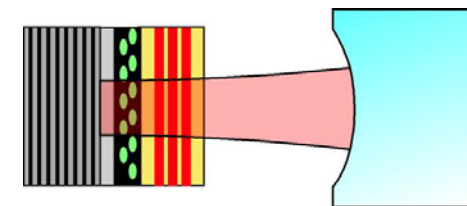
Vertical external cavity surface emitting laser (VECSEL) or semiconductor thin disk laser



Modelocked VECSEL



MIXSEL



Review article: U. Keller and A. C. Tropper, Physics Reports, vol. 429, Nr. 2, pp. 67-120, 2006

fast-dot.eu

**Fast Dot Project**

June 2008, 4 years



**FAST-DOT**

Project funding: 10.1 Mio Euro  
Consortium: 10 Uni, 7 Industries

SEVENTH FRAMEWORK PROGRAMME: Photonic Components and Subsystems  
COMPACT ULTRAFAST LASER SOURCES BASED ON NOVEL QUANTUM DOT STRUCTURES

nano-tera.ch

June 2009, 4 years



**nano-tera.ch**

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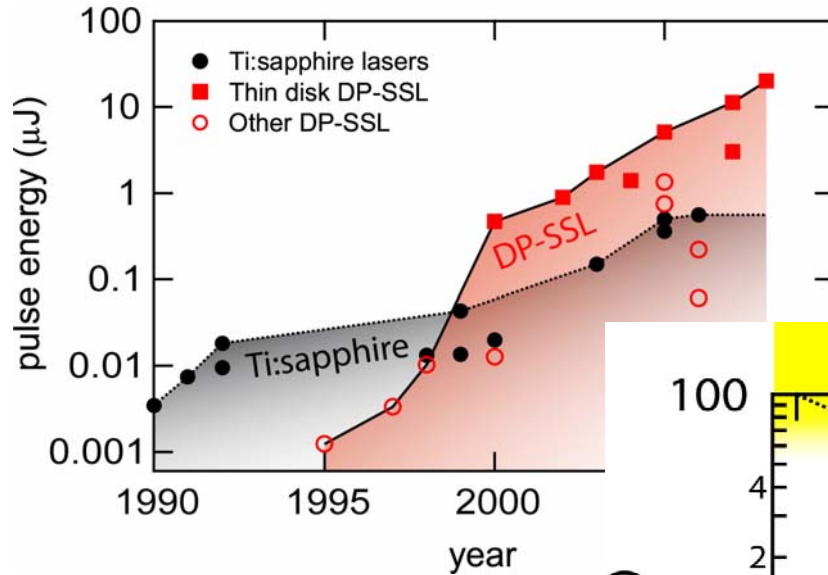


**MIXSEL Project funding: 2.3 Mio CHF  
Consortium: 4 Uni**

ENGINEERING COMPLEX SYSTEMS FOR HEALTH, SECURITY AND THE ENVIRONMENT



# High average power lasers - moving towards 100 μJ



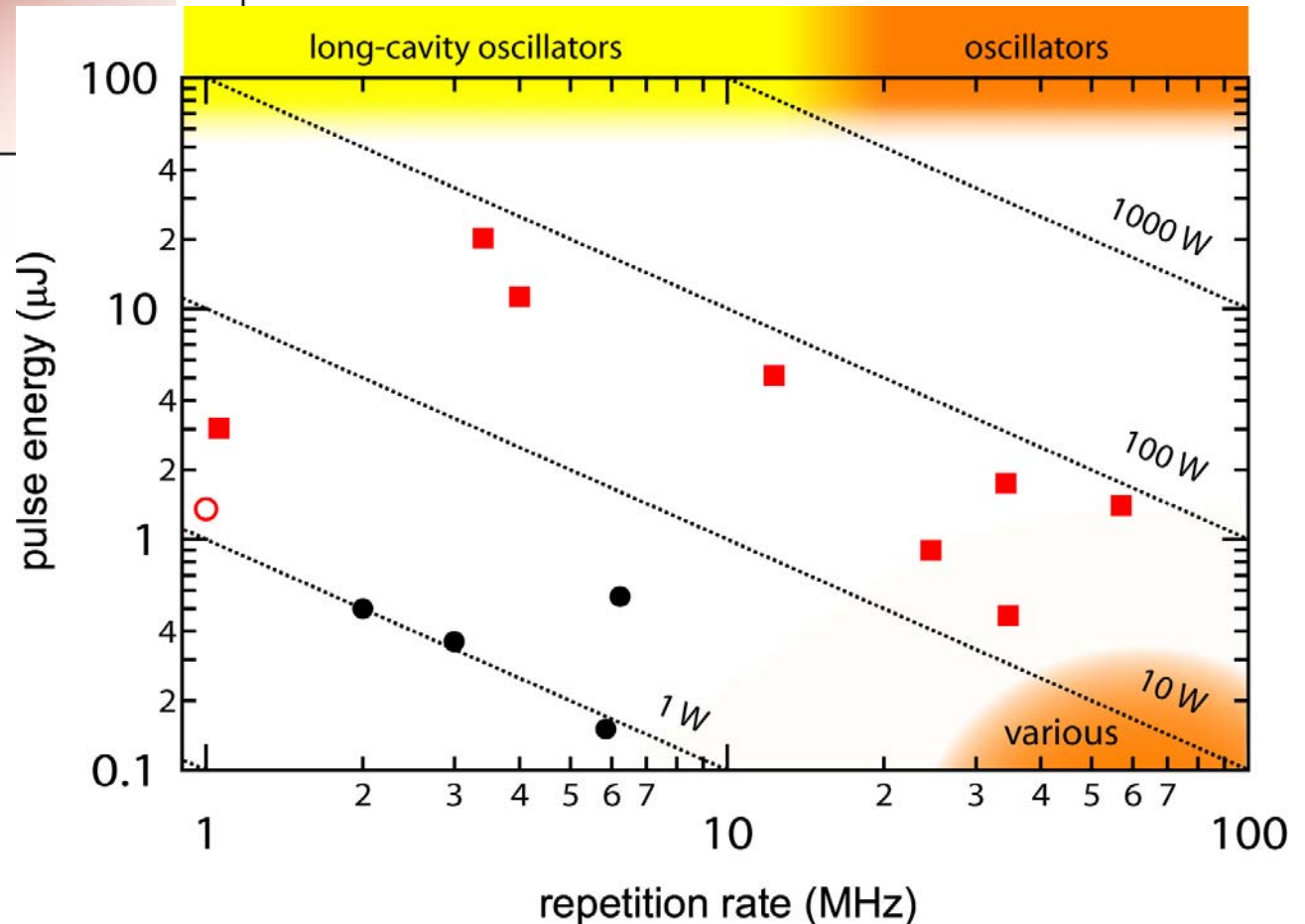
QuickTime™ and a TIFF (Uncompressed) decompressor are needed to see this picture.

100 μJ

5 MHz

500 W average power

$$P_{av} = E_p f_{rep}$$



# Keller group



## Ultrafast solid-state lasers: High average power (ML thin-disk laser)

Sergio Marchese, Cyrill Bär, Anna Enquist, Oliver Heckl, **Dr. Thomas Südmeyer** and *new: Clara Saraceno, Dr. Christian Kränkel*

## Ultrafast solid-state lasers: High pulse repetition rate

Max Stumpf, Andreas Oehler, Selina Pekarek, **Dr. Thomas Südmeyer**

## Ultrafast surface-emitting semiconductor lasers (ultrafast VECSELS and MIXSELS)

Deran Maas, Aude-Reine Bellancourt, Benjamin Rudin, Andreas Rutz, Martin Hoffmann, Dr. Yohan Barbarin, **Dr. Thomas Südmeyer** and *new: Valentin Wittwer, Oliver Sieber*

## MBE growth in ETH clean room facility (FIRST-lab)

Dr. Matthias Golling

## High field laser physics, attosecond pulse generation and science

**Dr. Lukas Gallmann**, Dr. Amelle Zair, Dr. Claudio Cirelli, Dr. Thomas Remetter, *new: Dr. Mathias Smolarski*  
Christian Erny, Petrissa Eckle, Mirko Holler, Florian Schlapper, Matthias Weger, Adrian Pfeiffer, Clemens Heese



end